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NC7S14 TinyLogic® HS Inverter with Schmitt Trigger Input

General Description

FAIRCHILD

SEMICONDUCTOR

The NC7S14 is a single high performance CMOS Inverter with Schmitt Trigger input. The circuit design provides hysteresis between the positive-going and negative going input thresholds thereby improving noise margins.

Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad V_{CC} range. ESD protection diodes inherently guard both input and output with respect to the V_{CC} and GND rails.

Features

- Space saving SOT23 or SC70 5-lead package
- Ultra small MicroPak[™] leadless package
- Schmitt input hysteresis: > 1V typ
- High speed: t_{PD} 4.5 ns typ
- Low quiescent power: I_{CC} < 1 μA</p>
- Balanced output drive: 2 mA I_{OL}, -2 mA I_{OH}
- Broad V_{CC} operating range: 2V 6V
- Balanced propagation delays
- Specified for 3V operation

Ordering Code:

Order Number	Package Number	Package Top Mark	Package Description	Supplied As	
NC7S14M5X	MA05B	7S14	5-Lead SOT23, JEDEC MO-178, 1.6mm	3k Units on Tape and Reel	
NC7S14P5X	MAA05A	S14	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3k Units on Tape and Reel	
NC7S14L6X	MAC06A	UU	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel	

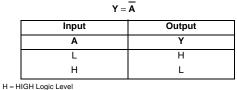
Logic Symbol



Pin Descriptions

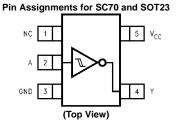
Pin Names	Description
A	Input
Y	Output
NC	No Connect

Function Table

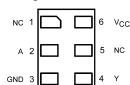


L = LOW Logic Level

Connection Diagrams



Pad Assignments for MicroPak



(Top Thru View)

 $\label{eq:transformation} TinyLogic \circledast is a registered trademark of Fairchild Semiconductor Corporation. \\ MicroPak^{ {\rm TM}} is a trademark of Fairchild Semiconductor Corporation. \\$

NC7S14

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Diode Current (IIK)	
$@V_{IN} \leq -0.5V$	–20 mA
$@V_{IN} \ge V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V _{IN})	–0.5V to V _{CC} +0.5V
DC Output Diode Current (I _{OK})	
$@V_{OUT} < -0.5V$	–20 mA
$@V_{OUT} > V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V _{OUT})	–0.5V to V _{CC} +0.5V
DC Output Source or Sink	
Current (I _{OUT})	±12.5 mA
DC V _{CC} or Ground Current per	
Output Pin (I _{CC} or I _{GND})	±25 mA
Storage Temperature (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Junction Temperature (T _J)	150°C
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C
Power Dissipation (P _D) @ +85°C	
SOT23-5	200 mW
SC70-5	150 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V _{CC})	2.0V to 6.0V
Input Voltage (V _{IN})	0V to V_{CC}
Output Voltage (V _{OUT})	0V to V_{CC}
Operating Temperature (T _A)	$-40^{\circ}C$ to $+85^{\circ}C$
Thermal Resistance (θ_{JA})	
SOT23-5	300°C/W
SC70-5	425°C/W

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of circuits outside the databook specifications. Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Vcc		$T_A = +25^{\circ}C$;	$T_A = -40^{\circ}$	C to +85°C	Units	Conditions
Symbol	Farameter	(V)	Min	Тур	Max	Min	Max	Units	Conditions
/ _P	Positive Threshold Voltage	2.0	1.0	1.29	1.5	1.0	1.6		
		3.0	1.5	1.90	2.2	1.5	2.2	V	
		4.5	2.3	2.73	3.15	2.3	3.15	v	
		6.0	3.0	3.56	4.2	3.0	4.2		
V _N	Negative Threshold Voltage	2.0	0.3	0.70	0.9	0.3	0.9		
		3.0	0.6	1.05	1.35	0.6	1.35	V	
		4.5	1.13	1.66	2.0	1.13	2.0	v	
		6.0	1.5	2.24	2.6	1.5	2.6		
V _H	Hysteresis Voltage	2.0	0.3	0.59	1.0	0.3	1.0		
		3.0	0.4	0.85	1.3	0.4	1.3	V	
		4.5	0.6	1.08	1.4	0.6	1.4	v	
		6.0	0.8	1.31	1.7	0.8	1.7		
V _{OH}	HIGH Level Output Voltage	2.0	1.90	2.0		1.90			
		3.0	2.90	3.0		2.90		V	$I_{OH} = -20 \ \mu A$
		4.5	4.40	4.5		4.40		v	$V_{IN} = V_{IL}$
		6.0	5.90	6.0		5.90			
									$V_{IN} = V_{IL}$
		3.0	2.68	2.87		2.63		V	$I_{OH} = -1.3 \text{ mA}$
		4.5	4.18	4.37		4.13		v	$I_{OH} = -2 \text{ mA}$
		6.0	5.68	5.86		5.63			$I_{OH} = -2.6 \text{ mA}$
/ _{OL}	LOW Level Output Voltage	2.0		0.0	0.10		0.10		
		3.0		0.0	0.10		0.10	v	$I_{OH} = 20 \ \mu A$
		4.5		0.0	0.10		0.10	v	$V_{IN}=V_{IH}$
		6.0		0.0	0.10		0.10		
									$V_{IN} = V_{IH}$
		3.0		0.1	0.26		0.33	v	$I_{OL} = 1.3 \text{ mA}$
		4.5		0.1	0.26		0.33	v	$I_{OL} = 2 \text{ mA}$
		6.0		0.1	0.26		0.33		I _{OL} = 2.6 mA

DC Electrical Characteristics (Continued)

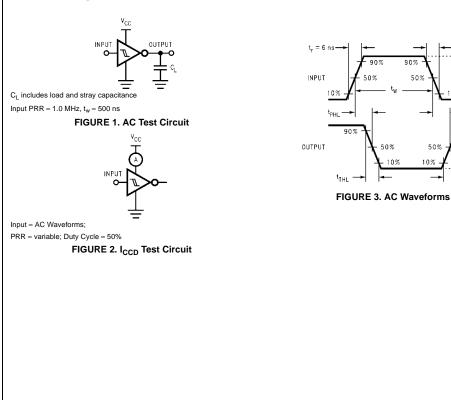
Symbol	Parameter	V _{cc}	$T_{A} = +25^{\circ}C$		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions		
Cymbol	i arameter	(V)	Min	Тур	Max	Min	Мах	onno	Conditions	
I _{IN}	Input Leakage Current	6.0			±0.1		±1.0	μA	$V_{IN} = V_{CC}, GND$	
I _{CC}	Quiescent Supply Current	6.0			1.0		10.0	μA	$V_{IN} = V_{CC}, GND$	

AC Electrical Characteristics

Symbol	Parameter	v _{cc}		$T_A = +25^{\circ}C$		$T_A = -40^{\circ}$	C to +85°C	Units	Conditions	Figure
c)	i arameter	(V)	Min	Тур	Max	Min	Max	onno		Number
t _{PLH}	Propagation Delay	5.0		4.5	21			ns	C _L = 15 pF	
t _{PHL}		2.0		20	100		125		C _L = 50 pF	-
		3.0		12	27		35		F	Figures 1, 3
		4.5		8.5	20		25	ns		., 0
		6.0		7.5	17		21			
t _{TLH}	Output Transition Time	5.0		3	8			ns	C _L = 15 pF	
t _{THL}		2.0		25	125		145		$C_L = 50 \text{ pF}$	1_
		3.0		16	35		45			Figures 1, 3
		4.5		11	25		30	ns		1, 0
		6.0		9	21		24			
CIN	Input Capacitance	Open		2	10		10	pF		
C _{PD}	Power Dissipation Capacitance	5.0		7				pF	(Note 3)	Figure 2

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 2.) C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC} static).

AC Loading and Waveforms



3

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= 6 ns

t_{PLH}

GND

90% ^Vон

 V_{OL}

— t_{TLH}

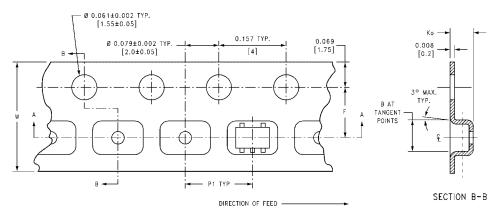
NC7S14

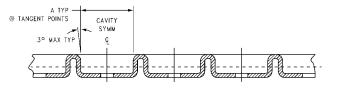
Tape and Reel Specification

TAPE FORMAT for SC70 and SOT23

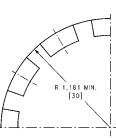
TAPE FORMAT for S	APE FORMAT for SC70 and SO123									
Package	Таре	Number	Cavity	Cover Tape						
Designator	Section	Cavities	Status	Status						
	Leader (Start End)	125 (typ)	Empty	Sealed						
M5X, P5X	Carrier	3000	Filled	Sealed						
	Trailer (Hub End)	75 (typ)	Empty	Sealed						

TAPE DIMENSIONS inches (millimeters)





SECTION A-A



BEND RADIUS NOT TO SCALE

Package	Tape Size	DIM A	DIM B	DIM F	DIM K _o	DIM P1	DIM W
SC70-5	8 mm	0.093	0.096	0.138 ±0.004	0.053 ±0.004	0.157	0.315 ±0.004
		(2.35)	(2.45)	(3.5 ±0.10)	(1.35 ±0.10)	(4)	(8 ±0.1)
SOT23-5	9 mm	0.130	0.130	0.138 ±0.002	0.055 ±0.004	0.157	0.315 ±0.012
	8 mm	(3.3)	(3.3)	(3.5 ±0.05)	(1.4 ±0.11)	(4)	(8 ±0.3)

